## NSN 5961-00-490-4259

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-490-4259 **Inclosure Material:** Metal **Overall Length:** 0.750 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 collector to emitter voltage, dc and 15.0 emitter to base voltage, instantaneous and 200.0 collector to base voltage, dc **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 wire hook and 2 tab, solder lug Shelf Life: N/a

**Demilitarization:** 

**Unit Of Measure:** 

Yes - demil/mli

## **NSN 5961-00-490-4259** Transistor - Page 2 of 2



Fiig:

A110a0